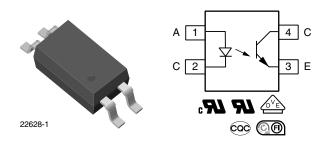
# VOS615A

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# Optocoupler, Phototransistor Output, Low Input Current, SSOP-4, Half Pitch, Mini-Flat Package



## DESCRIPTION

The VOS615A series has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4-pin 50 mil lead pitch mini-flat package.

It features a high current transfer ratio at low input current, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits.

### FEATURES

- High CTR with low input current
- Low profile package (half pitch)
- High collector emitter voltage,  $V_{CEO} = 80 \text{ V}$
- Isolation test voltage = 3750 V<sub>RMS</sub>
- Low coupling capacitance
- High common mode transient immunity
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

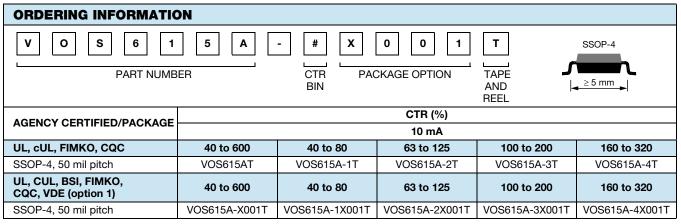
### **APPLICATIONS**

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines
- Programmable controllers

### AGENCY APPROVALS

Safety application model number covering all products in this datasheet is VOS615A. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60065, EN 60950-1
- CQC GB4943.1-2011 and GB8898-2011 (suitable for installation altitude below 2000 m)



#### Note

Additional options may be possible, please contact sales office.

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COMPLIANT HALOGEN FREE <u>GREEN</u> (5-2008)



| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                |                   |               |                  |  |  |  |
|---|----------------|-------------------|---------------|------------------|--|--|--|
| PARAMETER   | TEST CONDITION | SYMBOL            | VALUE         | UNIT             |  |  |  |
| INPUT   |                |                   |               |                  |  |  |  |
| Reverse voltage   |                | V <sub>R</sub>    | 6             | V                |  |  |  |
| Power dissipation   |                | P <sub>diss</sub> | 70            | mW               |  |  |  |
| Forward current   |                | I <sub>F</sub>    | 50            | mA               |  |  |  |
| OUTPUT  |                |                   |               |                  |  |  |  |
| Collector emitter voltage   |                | V <sub>CEO</sub>  | 80            | V                |  |  |  |
| Emitter collector voltage   |                | V <sub>ECO</sub>  | 7             | V                |  |  |  |
| Collector current   |                | Ι <sub>C</sub>    | 50            | mA               |  |  |  |
| Power dissipation   |                | P <sub>diss</sub> | 150           | mW               |  |  |  |
| COUPLER   |                |                   |               |                  |  |  |  |
| Isolation test voltage between emitter and detector                             | t = 1 min      | V <sub>ISO</sub>  | 3750          | V <sub>RMS</sub> |  |  |  |
| Total power dissipation   |                | P <sub>tot</sub>  | 170           | mW               |  |  |  |
| Storage temperature range   |                | T <sub>stg</sub>  | - 55 to + 150 | °C               |  |  |  |
| Ambient temperature range   |                | T <sub>amb</sub>  | - 55 to + 110 | °C               |  |  |  |
| Junction temperature  |                | Tj                | 125           | °C               |  |  |  |
| Soldering temperature <sup>(1)</sup>  | t = 10 s       | T <sub>sld</sub>  | 260           | °C               |  |  |  |

#### Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices.

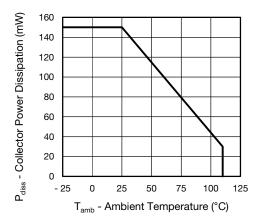


Fig. 1 - Power Dissipation vs. Ambient Temperature

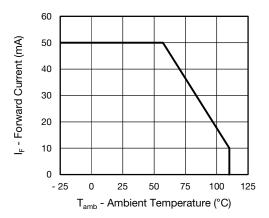


Fig. 2 - Forward Current vs. Ambient Temperature

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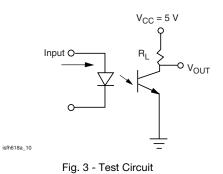
| ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                    |      |      |      |      |  |  |
|---|---|--------------------|------|------|------|------|--|--|
| PARAMETER   | TEST CONDITION                                      | SYMBOL             | MIN. | TYP. | MAX. | UNIT |  |  |
| INPUT   | INPUT   |                    |      |      |      |      |  |  |
| Forward voltage   | I <sub>F</sub> = 50 mA                              | V <sub>F</sub>     |      | 1.2  | 1.5  | V    |  |  |
| Reverse current   | V <sub>R</sub> = 6 V                                | I <sub>R</sub>     |      | 0.01 | 10   | μA   |  |  |
| Capacitance   | $V_R = 0 V, f = 1 MHz$                              | CI                 |      | 7.3  |      | pF   |  |  |
| OUTPUT  |   |                    |      |      |      |      |  |  |
| Collector emitter leakage current   | V <sub>CE</sub> = 10 V                              | I <sub>CEO</sub>   |      | 0.3  | 100  | nA   |  |  |
| Collector emitter breakdown voltage   | I <sub>C</sub> = 100 μA                             | BV <sub>CEO</sub>  | 80   |      |      | V    |  |  |
| Emitter collector breakdown voltage   | I <sub>E</sub> = 10 μA                              | BV <sub>ECO</sub>  | 7    |      |      | V    |  |  |
| Collector emitter capacitance   | $V_{CE} = 5 V, f = 1 MHz$                           | C <sub>CE</sub>    |      | 5    |      | pF   |  |  |
| COUPLER   |   |                    |      |      |      |      |  |  |
| Collector emitter saturation voltage  | I <sub>F</sub> = 10 mA, I <sub>C</sub> = 2.5 mA     | V <sub>CEsat</sub> |      | 0.25 | 0.4  | V    |  |  |
| Cut-off frequency   | $I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 100 $\Omega$ | f <sub>ctr</sub>   |      | 155  |      | kHz  |  |  |

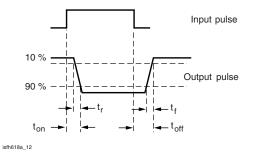
#### Note

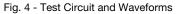
• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |           |        |      |      |      |      |
|---|---|-----------|--------|------|------|------|------|
| PARAMETER   | TEST CONDITION                                | PART      | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I <sub>C</sub> /I <sub>F</sub>  | I <sub>F</sub> = 10 mA, V <sub>CE</sub> = 5 V | VOS615A   | CTR    | 50   |      | 600  | %    |
|   |   | VOS615A-1 | CTR    | 40   |      | 80   | %    |
|   |   | VOS615A-2 | CTR    | 63   |      | 125  | %    |
|   |   | VOS615A-3 | CTR    | 100  |      | 200  | %    |
|   |   | VOS615A-4 | CTR    | 160  |      | 320  | %    |

| SWITCHING CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                  |      |      |      |      |
|--|---|------------------|------|------|------|------|
| PARAMETER  | TEST CONDITION  | SYMBOL           | MIN. | TYP. | MAX. | UNIT |
| NON-SATURATED  |   |                  |      |      |      |      |
| Rise and fall time   |   | t <sub>r</sub>   |      | 3    |      | μs   |
| Fall time  | $I_{\rm C} = 2 \text{ mA}, V_{\rm CC} = 5 \text{ V},$         | t <sub>f</sub>   |      | 4    |      | μs   |
| Turn-on time   | $R_L = 100 \Omega$  | t <sub>on</sub>  |      | 5    |      | μs   |
| Turn-off time  |   | t <sub>off</sub> |      | 5    |      | μs   |
| SATURATED  |   |                  |      |      |      |      |
| Rise and fall time   | $I_{F}$ = 1.6 mA, $V_{CC}$ = 5 V,<br>$R_{L}$ = 1.9 k $\Omega$ | t <sub>r</sub>   |      | 3    |      | μs   |
| Fall time  |   | t <sub>f</sub>   |      | 12   |      | μs   |
| Turn-on time   |   | t <sub>on</sub>  |      | 4    |      | μs   |
| Turn-off time  |   | t <sub>off</sub> |      | 18   |      | μs   |







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| SAFETY AND INSULATION RATINGS                    |  |                   |                   |                   |  |  |
|--|--|-------------------|-------------------|-------------------|--|--|
| PARAMETER  | SYMBOL   | VALUE             | UNIT              |                   |  |  |
| MAXIMUM SAFETY RATINGS                           |  |                   |                   |                   |  |  |
| Output safety power                              |  | P <sub>SO</sub>   | 300               | mW                |  |  |
| Input safety current                             |  | I <sub>si</sub>   | 200               | mA                |  |  |
| Safety temperature                               | Τ <sub>S</sub>                                 | 150               | °C                |                   |  |  |
| Comparative tracking index                       |  | CTI               | 175               |                   |  |  |
| INSULATION RATED PARAMETERS                      |  |                   |                   |                   |  |  |
| Maximum withstanding isolation voltage           | 40 % to 60 % RH, AC test of 1 min              | V <sub>ISO</sub>  | 3750              | V <sub>RMS</sub>  |  |  |
| Maximum transient isolation voltage              | V <sub>IOTM</sub>                              | 6000              | V <sub>peak</sub> |                   |  |  |
| Maximum repetitive peak isolation voltage        |  | V <sub>IORM</sub> | 565               | V <sub>peak</sub> |  |  |
| Insulation resistance                            | $T_{amb} = 25 \ ^{\circ}C, \ V_{DC} = 500 \ V$ | R <sub>IO</sub>   | 10 <sup>12</sup>  | Ω                 |  |  |
| Isolation resistance                             | $T_{amb} = 100 \ ^{\circ}C, V_{DC} = 500 \ V$  | R <sub>IO</sub>   | 10 <sup>11</sup>  | Ω                 |  |  |
| Climatic classification (according to IEC 68 par |  | 55/110/21         |                   |                   |  |  |
| Environment (pollution degree in accordance to   | DIN VDE 0109)                                  |                   | 2                 |                   |  |  |
| Creepage distance                                |  |                   | ≥ 5               | mm                |  |  |
| Clearance distance                               |  |                   | ≥ 5               | mm                |  |  |
| Insulation thickness                             | DTI  | ≥ 0.4             | mm                |                   |  |  |

Note

• As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

# TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

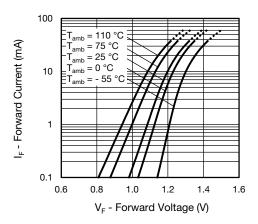


Fig. 5 - Forward Voltage vs. Forward Current

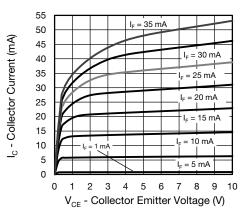
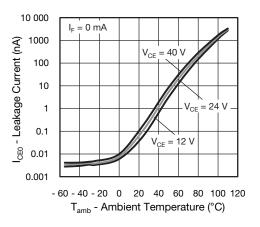


Fig. 6 - Collector Current vs. Collector Emitter Voltage

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Fig. 7 - Leakage Current vs. Ambient Temperature

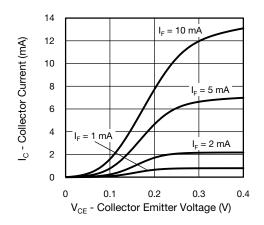


Fig. 8 - Collector Current vs. Collector Emitter Voltage

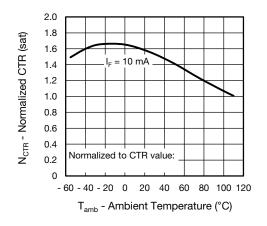


Fig. 9 - Normalized Current Transfer Ratio (sat) vs. Ambient Temperature

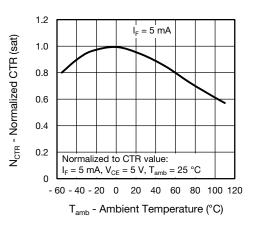


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs. Ambient Temperature

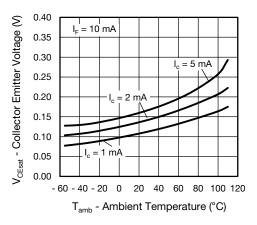


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature

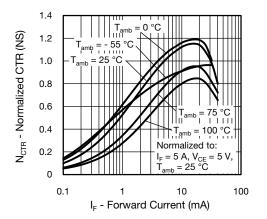
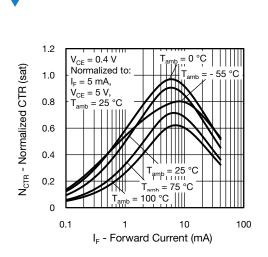


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current

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Fig. 13 - Normalized CTR (saturated) vs. Forward Current

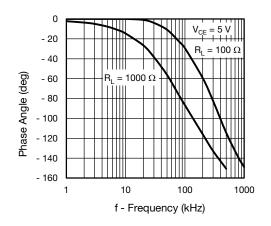


Fig. 14 - F<sub>CTR</sub> vs. Phase Angle

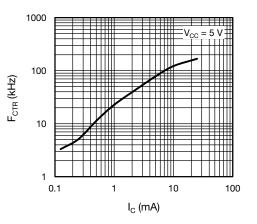


Fig. 15 - F<sub>CTR</sub> vs. Collector Current

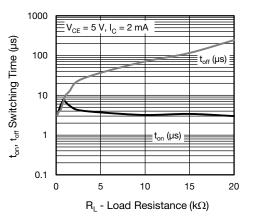
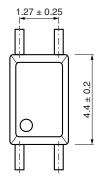


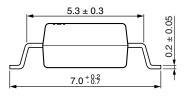
Fig. 16 - Switching Time vs. Load Resistance

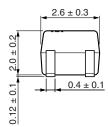
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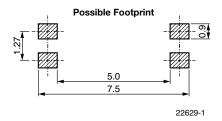


### **PACKAGE DIMENSIONS** in millimeters

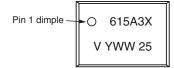








### PACKAGE MARKING (example VOS615A-3X001T)



#### Notes

- Option 1 is reflected with letter "X".
- Tape and reel suffix (T) is not part of the package marking.

## TAPE AND REEL DIMENSIONS in millimeters

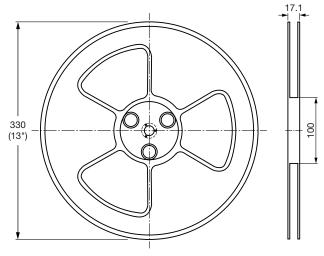


Fig. 17 - Reel Dimensions (3000 units per reel)

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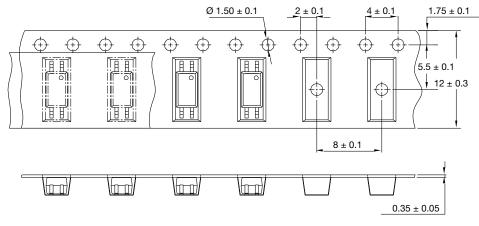


Fig. 18 - Tape Dimensions



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